Small Signal MOSFET

60 V, 380 mA, Single, N-Channel, SOT-23

Features

- ESD Protected
- Low R_{DS(on)}
- Surface Mount Package
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

Applications

- Low Side Load Switch
- Level Shift Circuits
- DC-DC Converter
- Portable Applications i.e. DSC, PDA, Cell Phone, etc.

$\textbf{MAXIMUM RATINGS} \quad (T_J = 25^{\circ}C \text{ unless otherwise stated})$

Rating	Symbol	Value	Unit	
Drain-to-Source Voltage	V_{DSS}	60	V	
Gate-to-Source Voltage	Gate-to-Source Voltage			V
Drain Current (Note 1) Steady State	T _A = 25°C T _A = 85°C	Ι _D	320 230	mA
t < 5 s	$T_A = 25$ °C $T_A = 85$ °C		380 270	
Power Dissipation (Note 1) Steady State t < 5 s		P _D	300 420	mW
Pulsed Drain Current (t _p = 10 μs)		I_{DM}	1.5	Α
Operating Junction and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C	
Source Current (Body Diode)	I _S	300	mA	
Lead Temperature for Soldering (1/8" from case for 10 s)	T _L	260	°C	
Gate-Source ESD Rating (HBM, Method 3015)	ESD	2000	V	

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Junction-to-Ambient - Steady State (Note 1)	$R_{ heta JA}$	417	°C/W
Junction-to-Ambient – $t \le 5$ s (Note 1)	$R_{\theta JA}$	300	

Surface-mounted on FR4 board using 1 in sq pad size (Cu area = 1.127 in sq [1 oz] including traces)

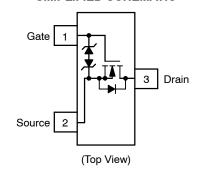


ON Semiconductor®

http://onsemi.com

V _{(BR)DSS}	R _{DS(on)} MAX	I _D MAX (Note 1)
60 V	1.6 Ω @ 10 V	380 mA
	2.5 Ω @ 4.5 V	

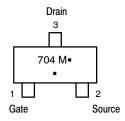
SIMPLIFIED SCHEMATIC



MARKING DIAGRAM & PIN ASSIGNMENT



SOT-23 CASE 318 STYLE 21



704 = Specific Device Code

M = Date Code

= Pb-Free Package

(Note: Microdot may be in either location)

*Date Code orientation and/or position may vary depending upon manufacturing location.

ORDERING INFORMATION

Device	Package	Shipping [†]
2N7002KT1G	SOT-23 (Pb-Free)	3000/Tape & Reel
2N7002KT1H	SOT-23 (Pb-Free)	3000/Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

ELECTRICAL CHARACTERISTICS ($T_J = 25^{\circ}C$ unless otherwise specified)

Parameter	Symbol	Test Condition		Min	Тур	Max	Units
OFF CHARACTERISTICS				•			
Drain-to-Source Breakdown Voltage	V _{(BR)DSS}	V_{GS} = 0 V, I_{D} = 250 μA		60			V
Drain-to-Source Breakdown Voltage Temperature Coefficient	V _{(BR)DSS} /T _J				71		mV/°C
Zero Gate Voltage Drain Current	I _{DSS}	V _{GS} = 0 V,	T _J = 25°C			1	μΑ
		V _{DS} = 60 V	T _J = 125°C			500	1
		V _{GS} = 0 V, V _{DS} = 50 V	T _J = 25°C			100	nA
Gate-to-Source Leakage Current	I _{GSS}	V _{DS} = 0 V, V _{GS} = ±20 V				±10	μΑ
		V _{DS} = 0 V, \	/ _{GS} = ±10 V			450	nA
		V _{DS} = 0 V, V _{GS} = ±5.0 V				150	nA
ON CHARACTERISTICS (Note 2)				•	•		•
Gate Threshold Voltage	V _{GS(TH)}	$V_{GS} = V_{DS}$	I _D = 250 μA	1.0		2.3	V
Negative Threshold Temperature Coefficient	V _{GS(TH)} /T _J				4.0		mV/°C
Drain-to-Source On Resistance	R _{DS(on)}	$R_{DS(on)}$ $V_{GS} = 10 \text{ V}, I_D = 500 \text{ mA}$			1.19	1.6	Ω
		V _{GS} = 4.5 V, I _D = 200 mA			1.33	2.5]
Forward Transconductance	9 _F s	V _{DS} = 5 V, I _D = 200 mA			530		mS
CHARGES AND CAPACITANCES							
Input Capacitance	C _{ISS}	$V_{GS} = 0 \text{ V, f} = 1 \text{ MHz,}$ $V_{DS} = 20 \text{ V}$			24.5		pF
Output Capacitance	C _{OSS}				4.2		
Reverse Transfer Capacitance	C _{RSS}	· DS ·	- 20 •		2.2		
Total Gate Charge	Q _{G(TOT)}				0.7		nC
Threshold Gate Charge	Q _{G(TH)}	V _{GS} = 4.5 V, V _{DS} = 10 V;			0.1		
Gate-to-Source Charge	Q _{GS}		00 mA		0.3]
Gate-to-Drain Charge	Q_{GD}	1			0.1		
SWITCHING CHARACTERISTICS, V_{GS}	= V (Note 3)						
Turn-On Delay Time	t _{d(ON)}	V_{GS} = 10 V, V_{DD} = 25 V, I_{D} = 500 mA, R_{G} = 25 Ω			12.2		ns
Rise Time	t _r				9.0		}
Turn-Off Delay Time	t _{d(OFF)}				55.8		
Fall Time	t _f				29		
DRAIN-SOURCE DIODE CHARACTER	ISTICS						
Forward Diode Voltage	V _{SD}	V _{GS} = 0 V,	T _J = 25°C		0.8	1.2	V
		I _S = 200 mA			0.7		

Pulse Test: pulse width ≤ 300 μs, duty cycle ≤ 2%
 Switching characteristics are independent of operating junction temperatures

TYPICAL CHARACTERISTICS

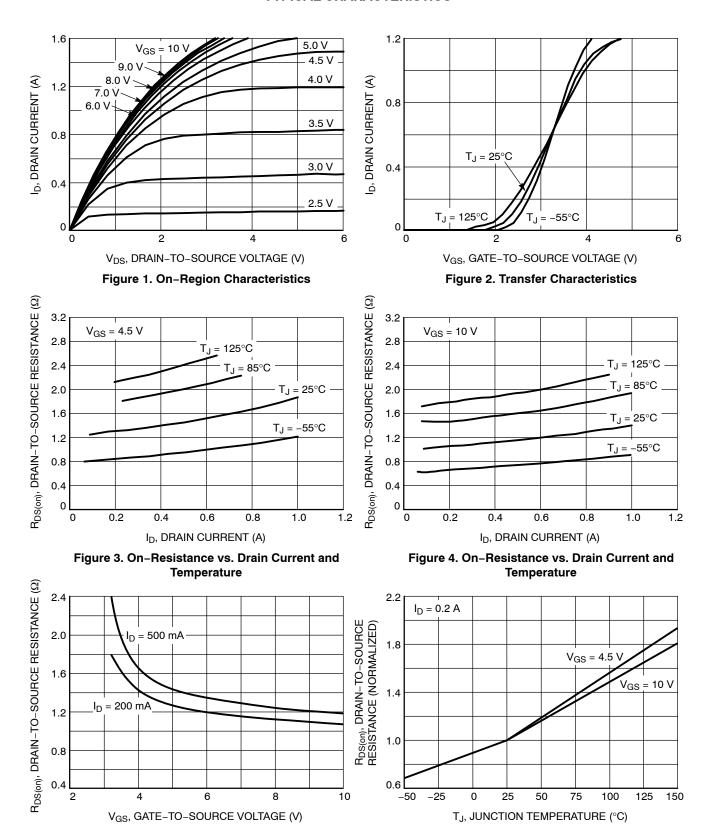
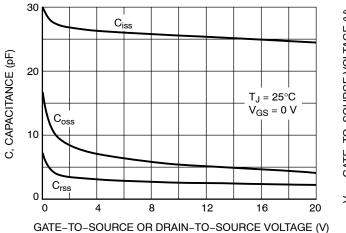


Figure 5. On-Resistance vs. Gate-to-Source Voltage

Figure 6. On–Resistance Variation with Temperature

TYPICAL CHARACTERISTICS



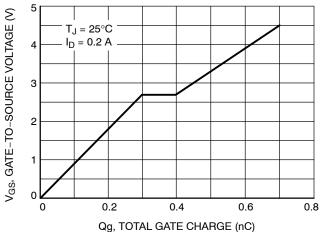


Figure 7. Capacitance Variation

Figure 8. Gate-to-Source and Drain-to-Source Voltage vs. Total Charge

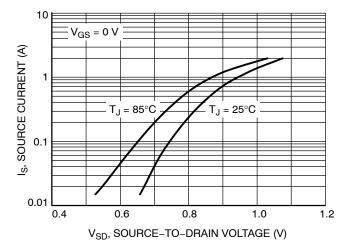
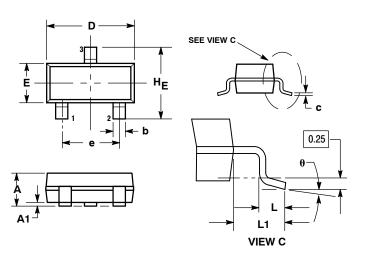


Figure 9. Diode Forward Voltage vs. Current

PACKAGE DIMENSIONS

SOT-23 (TO-236) CASE 318-08 **ISSUE AP**



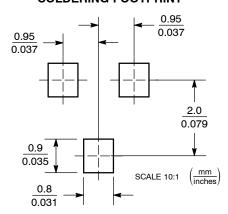
- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: INCH.
 MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
 DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH,
- PROTRUSIONS, OR GATE BURRS

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.89	1.00	1.11	0.035	0.040	0.044
A1	0.01	0.06	0.10	0.001	0.002	0.004
b	0.37	0.44	0.50	0.015	0.018	0.020
С	0.09	0.13	0.18	0.003	0.005	0.007
D	2.80	2.90	3.04	0.110	0.114	0.120
Е	1.20	1.30	1.40	0.047	0.051	0.055
е	1.78	1.90	2.04	0.070	0.075	0.081
L	0.10	0.20	0.30	0.004	0.008	0.012
L1	0.35	0.54	0.69	0.014	0.021	0.029
HE	2.10	2.40	2.64	0.083	0.094	0.104
θ	0°		10°	0°		10°

STYLE 21:

- PIN 1. GATE
 - SOURCE DRAIN 2.

SOLDERING FOOTPRINT



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